

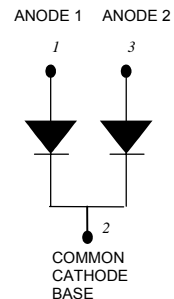
SDUR6030WT ULTRAFAST PLASTIC RECTIFIER

Applications:

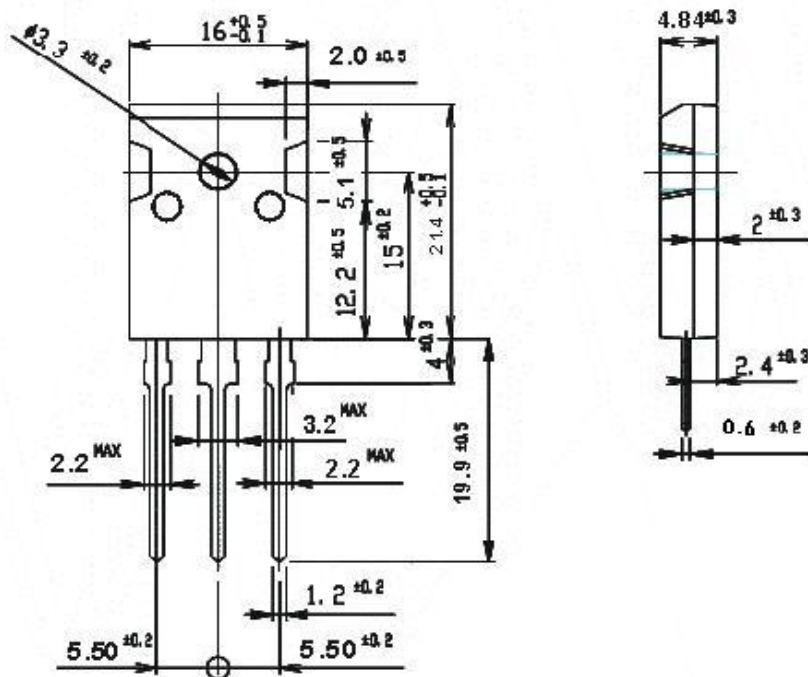
- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Features:

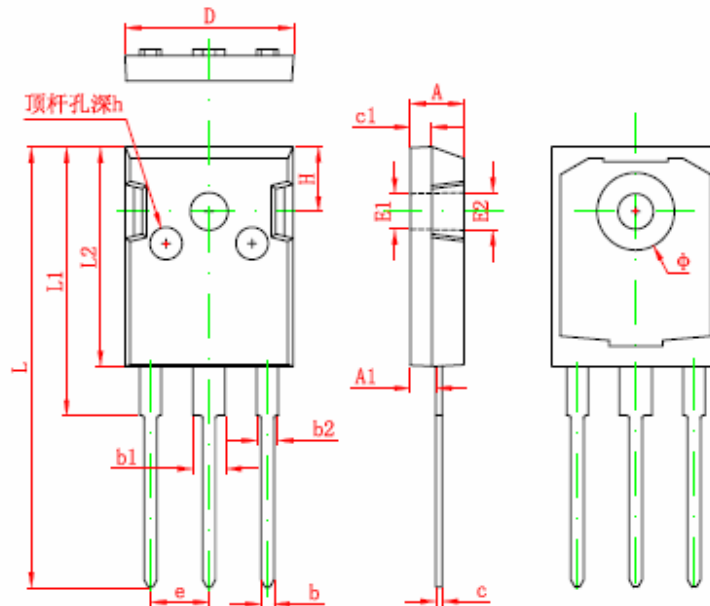
- Ultra-Fast Switching
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-0
- This is a Pb - Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



Mechanical Dimensions: In mm/Inches



OPTION 1(SR)

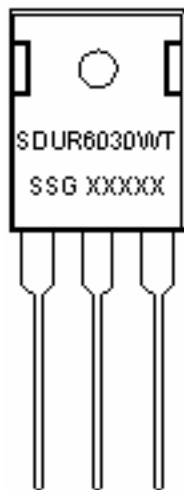


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	4.850	5.150	0.191	0.200
A1	2.200	2.600	0.087	0.102
b	1.000	1.400	0.039	0.055
b1	2.800	3.200	0.110	0.126
b2	1.800	2.200	0.071	0.087
c	0.500	0.700	0.020	0.028
c1	1.900	2.100	0.075	0.083
D	15.450	15.750	0.608	0.620
E1	3.500 REF		0.138 REF	
E2	3.600 REF		0.142 REF	
L	40.900	41.300	1.610	1.626
L1	24.800	25.100	0.976	0.988
L2	20.300	20.600	0.799	0.811
phi	7.100	7.300	0.280	0.287
e	5.450 TYP		0.215 TYP	
H	5.980 REF		0.235 REF	
h	0.000	0.300	0.000	0.012

OPTION 2(CJ)

TO-247AD

Marking Diagram:



Where XXXXX is YYWWL

SDUR = Device Type
60 = Forward Current (60A)
30 = Reverse Voltage (300V)
WT = Configuration
SSG = SSG
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin
Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
SDUR6030WT	TO-247AD (Pb-Free)	30 pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	300	V
Average Forward Current	$I_{F(AV)}$	50% duty cycle @Tc=100°C, rectangular wave form	60	A
Peak One Cycle Non-Repetitive Surge Current (Per leg)	I_{FSM}	8.3ms, Half Sine pulse	400	A

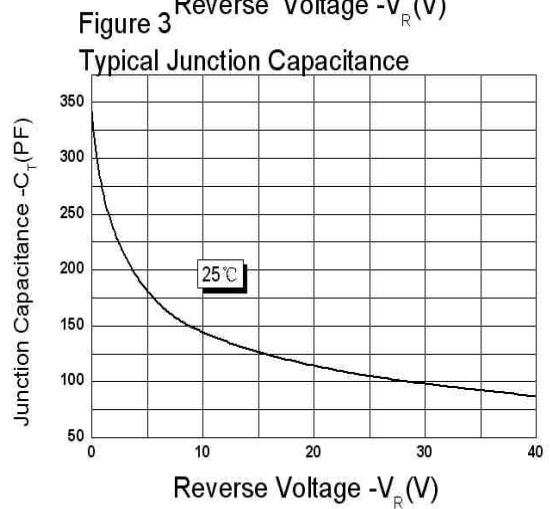
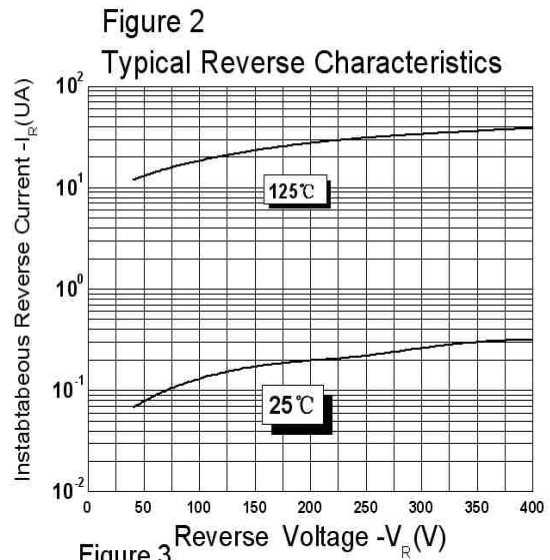
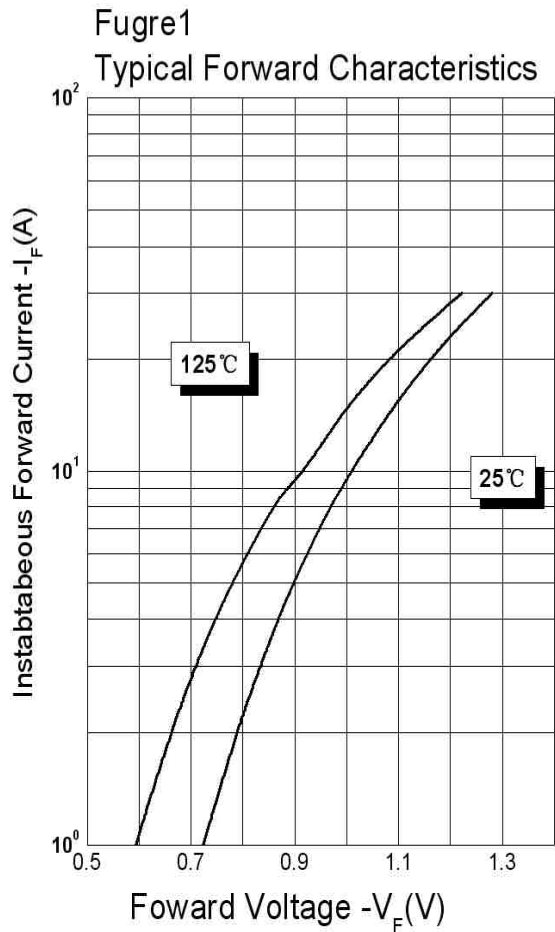
Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop(Per leg)*	V _{F1}	@ 30A, Pulse, T _J = 25°C	1.3	V
	V _{F2}	@ 30A, Pulse, T _J = 150°C	1.1	V
Reverse Current*	I _{R1}	@V _R = rated V _R T _J = 25°C	5.0	μA
	I _{R2}	@V _R = rated V _R T _J = 125°C	1.0	mA
Reverse Recovery Time	t _{rr1}	I _F =500mA, I _R =1A,and I _{rm} =250mA	45	ns

* Pulse width < 300 μs, duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T _J	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case	R _{θJC}	DC operation	2	°C/W
Approximate Weight	wt	-	6.28	g
Case Style	TO-247AD			



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